



# STC03DE220HV

Hybrid emitter switched bipolar transistor  
ESBT® 2200 V - 3 A - 0.33 Ω

## Features

| $V_{CS(ON)}$ | $I_C$ | $R_{CS(ON)}$ |
|--------------|-------|--------------|
| 1 V          | 3 A   | 0.33 Ω       |

- Low equivalent on resistance
- Very fast-switch, up to 150 kHz
- Very low  $C_{ISS}$  driven by  $R_G = 4.7 \Omega$

## Application

- Aux SMPS for three phase mains

## Description

The STC03DE220HV is manufactured in a hybrid structure, using dedicated high voltage bipolar and low voltage MOSFET technologies, aimed to providing the best performance in ESBT topology. The STC03DE220HV is designed for use in aux flyback SMPS for any three phase application.

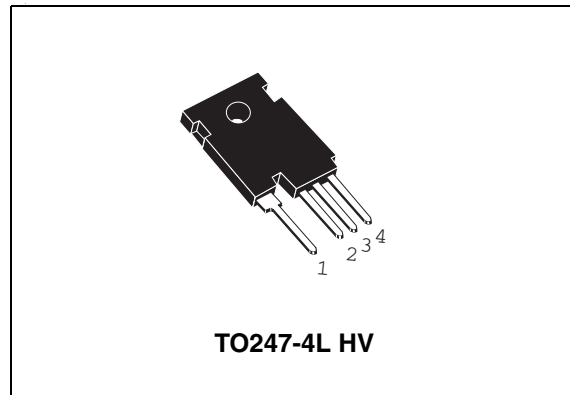


Figure 1. Internal schematic diagrams

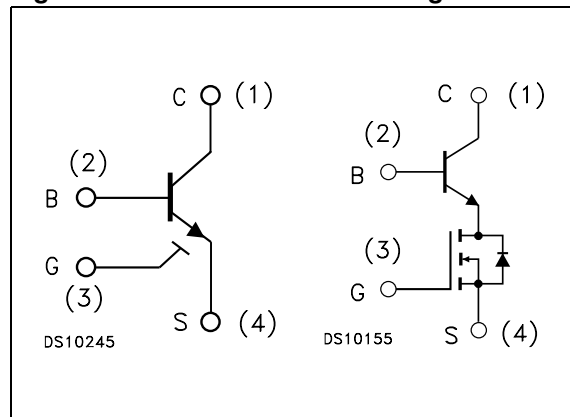


Table 1. Device summary

| Order code   | Marking    | Package     | Packaging |
|--------------|------------|-------------|-----------|
| STC03DE220HV | C03DE220HV | TO247-4L HV | Tube      |

# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

| Symbol       | Parameter  | Value      | Unit |
|--------------|--|------------|------|
| $V_{CS(SS)}$ | Collector-source voltage ( $V_{BS} = V_{GS} = 0$ ) | 2200       | V    |
| $V_{BS(OS)}$ | Base-source voltage ( $I_C = 0, V_{GS} = 0$ )      | 30         | V    |
| $V_{SB(OS)}$ | Source-base voltage ( $I_C = 0, V_{GS} = 0$ )      | 9          | V    |
| $V_{GS}$     | Gate-source voltage                                | $\pm 20$   | V    |
| $I_C$        | Collector current                                  | 3          | A    |
| $I_{CM}$     | Collector peak current ( $t_p < 5$ ms)             | 6          | A    |
| $I_B$        | Base current                                       | 3          | A    |
| $I_{BM}$     | Base peak current ( $t_p < 1$ ms)                  | 6          | A    |
| $P_{tot}$    | Total dissipation at $T_c \leq 25$ °C              | 166        | W    |
| $T_{stg}$    | Storage temperature                                | -40 to 150 | °C   |
| $T_J$        | Max. operating junction temperature                | 125        | °C   |

**Table 3. Thermal data**

| Symbol     | Parameter                        | Value | Unit |
|------------|----------------------------------|-------|------|
| $R_{thJC}$ | Thermal resistance junction-case | 0.6   | °C/W |

## 2 Electrical characteristics

( $T_{\text{case}} = 25\text{ }^{\circ}\text{C}$ ; unless otherwise specified)

**Table 4. Electrical characteristics**

| Symbol                           | Parameter   | Test conditions   | Min. | Typ.        | Max. | Unit          |
|----------------------------------|---|---|------|-------------|------|---------------|
| $I_{\text{CS(SS)}}$              | Collector cut-off current ( $V_{\text{BS}} = V_{\text{GS}} = 0$ ) | $V_{\text{CS}} = 2200\text{ V}$   |      |             | 100  | $\mu\text{A}$ |
| $I_{\text{BS(OS)}}$              | Base cut-off current ( $I_{\text{C}} = 0, V_{\text{GS}} = 0$ )    | $V_{\text{BS}} = 30\text{ V}$   |      |             | 10   | $\mu\text{A}$ |
| $I_{\text{SB(OS)}}$              | Source cut-off current ( $I_{\text{C}} = 0, V_{\text{GS}} = 0$ )  | $V_{\text{SB}} = 9\text{ V}$  |      |             | 100  | $\mu\text{A}$ |
| $I_{\text{GS(OS)}}$              | Gate-source leakage current ( $V_{\text{BS}} = 0$ )               | $V_{\text{GS}} = \pm 20\text{ V}$   |      |             | 500  | nA            |
| $V_{\text{CS(ON)}}$              | Collector-source ON voltage                                       | $V_{\text{GS}} = 10\text{ V } I_{\text{C}} = 1.5\text{ A } I_{\text{B}} = 0.15\text{ A}$<br>$V_{\text{GS}} = 10\text{ V } I_{\text{C}} = 3\text{ A } I_{\text{B}} = 0.6\text{ A}$   |      | 0.2<br>0.25 |      | V<br>V        |
| $h_{\text{FE}}$                  | DC current gain   | $V_{\text{CS}} = 1\text{ V } V_{\text{GS}} = 10\text{ V } I_{\text{C}} = 1.5\text{ A}$<br>$V_{\text{CS}} = 1\text{ V } V_{\text{GS}} = 10\text{ V } I_{\text{C}} = 3\text{ A}$  |      | 15<br>10    |      |               |
| $V_{\text{BS(ON)}}$              | Base-source ON voltage  | $V_{\text{GS}} = 10\text{ V } I_{\text{C}} = 1.5\text{ A } I_{\text{B}} = 0.15\text{ A}$<br>$V_{\text{GS}} = 10\text{ V } I_{\text{C}} = 3\text{ A } I_{\text{B}} = 0.6\text{ A}$   |      | 0.82<br>1   |      | V<br>V        |
| $V_{\text{GS(th)}}$              | Gate threshold voltage  | $V_{\text{BS}} = V_{\text{GS}} I_{\text{B}} = 250\text{ }\mu\text{A}$   | 1.5  | 2.2         | 3    | V             |
| $C_{\text{iss}}$                 | Input capacitance ( $V_{\text{GS}} = V_{\text{CB}} = 0$ )         | $V_{\text{CS}} = 25\text{ V } f = 1\text{ MHz}$   |      | 750         |      | pF            |
| $Q_{\text{GS(tot)}}$             | Gate-source Charge ( $V_{\text{CB}} = 0$ )                        | $V_{\text{CS}} = 15\text{ V } V_{\text{GS}} = 10\text{ V}$<br>$I_{\text{C}} = 1.8\text{ A}$   |      | 12.5        |      | nC            |
| $t_{\text{s}}$<br>$t_{\text{f}}$ | INDUCTIVE LOAD<br>Storage time<br>Fall time                       | $V_{\text{GS}} = 10\text{ V } R_{\text{G}} = 47\text{ }\Omega$<br>$V_{\text{Clamp}} = 1760\text{ V } t_{\text{p}} = 4\text{ }\mu\text{s}$<br>$I_{\text{C}} = 1.5\text{ A } I_{\text{B}} = 0.3\text{ A}$   |      | 1040<br>20  |      | ns<br>ns      |
| $V_{\text{CS(dyn)}}$             | Collector-source dynamic voltage (0.5 $\mu\text{s}$ )             | $V_{\text{CC}} = V_{\text{Clamp}} = 400\text{ V}$<br>$V_{\text{GS}} = 10\text{ V } I_{\text{C}} = 1.5\text{ A}$<br>$I_{\text{B}} = 0.3\text{ A } R_{\text{G}} = 47\text{ }\Omega$<br>$t_{\text{peak}} = 500\text{ ns } I_{\text{Bpeak}} = 3\text{ A}$ |      | 7.6         |      | V             |
| $V_{\text{CS(dyn)}}$             | Collector-source dynamic voltage (1 $\mu\text{s}$ )               | $V_{\text{CC}} = V_{\text{Clamp}} = 400\text{ V}$<br>$V_{\text{GS}} = 10\text{ V } I_{\text{C}} = 1.5\text{ A}$<br>$I_{\text{B}} = 0.3\text{ A } R_{\text{G}} = 47\text{ }\Omega$<br>$t_{\text{peak}} = 500\text{ ns } I_{\text{Bpeak}} = 3\text{ A}$ |      | 5.8         |      | V             |
| $V_{\text{CSW}}$                 | Maximum collector-source voltage at turn-off without snubber      | $R_{\text{G}} = 47\text{ }\Omega } h_{\text{FE}} = 5 } I_{\text{C}} = 3\text{ A}$   | 2200 |             |      | V             |

## 2.1 Electrical characteristics (curves)

Figure 2. DC current gain

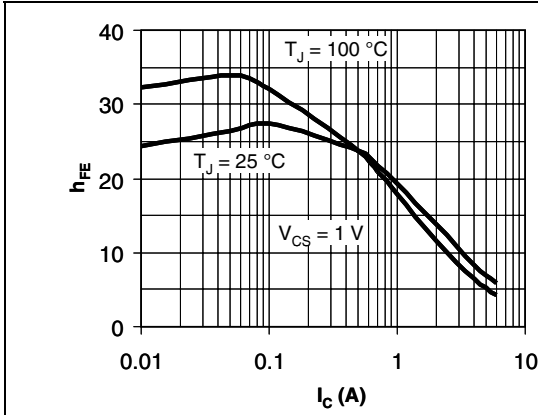


Figure 3. Base-source ON voltage

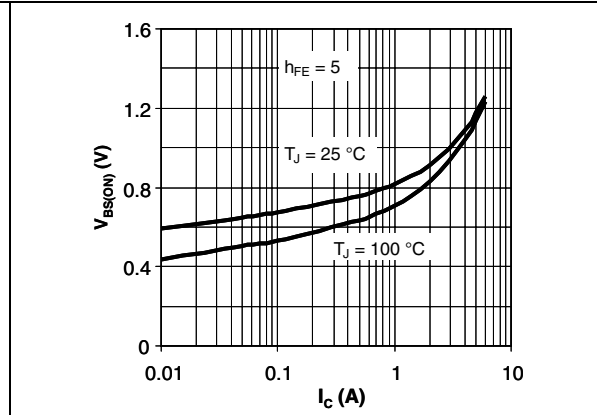


Figure 4. Collector-source ON voltage

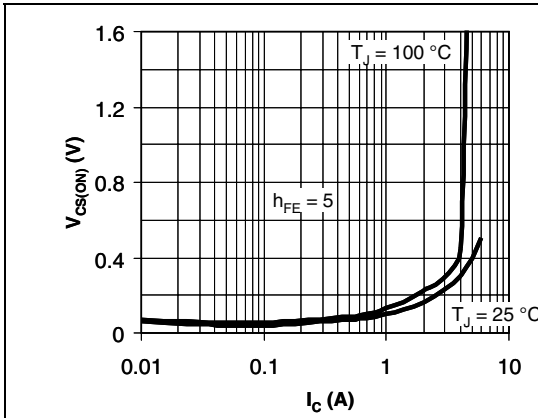


Figure 5. Collector-source dynamic voltage

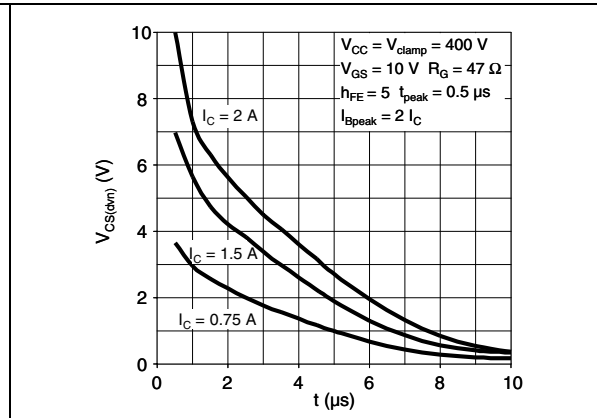


Figure 6. Inductive load switching off ( $T_C = 25^\circ\text{C}$ )

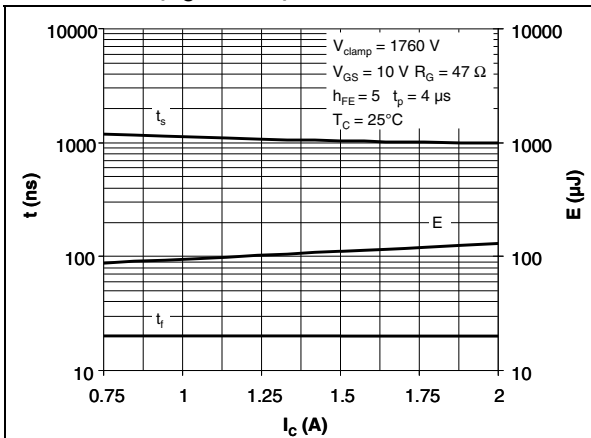


Figure 7. Inductive load switching off ( $T_C = 100^\circ\text{C}$ )

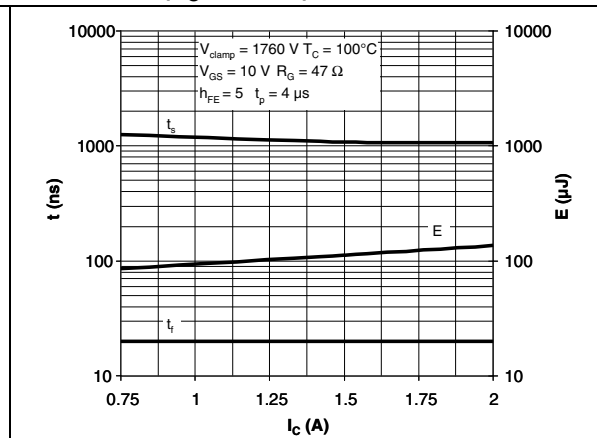
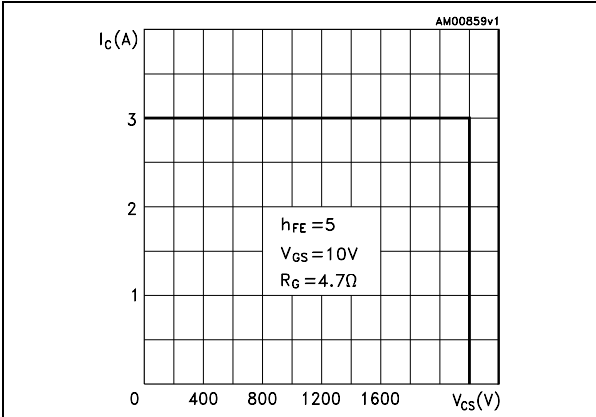


Figure 8. Reverse biased safe operating area

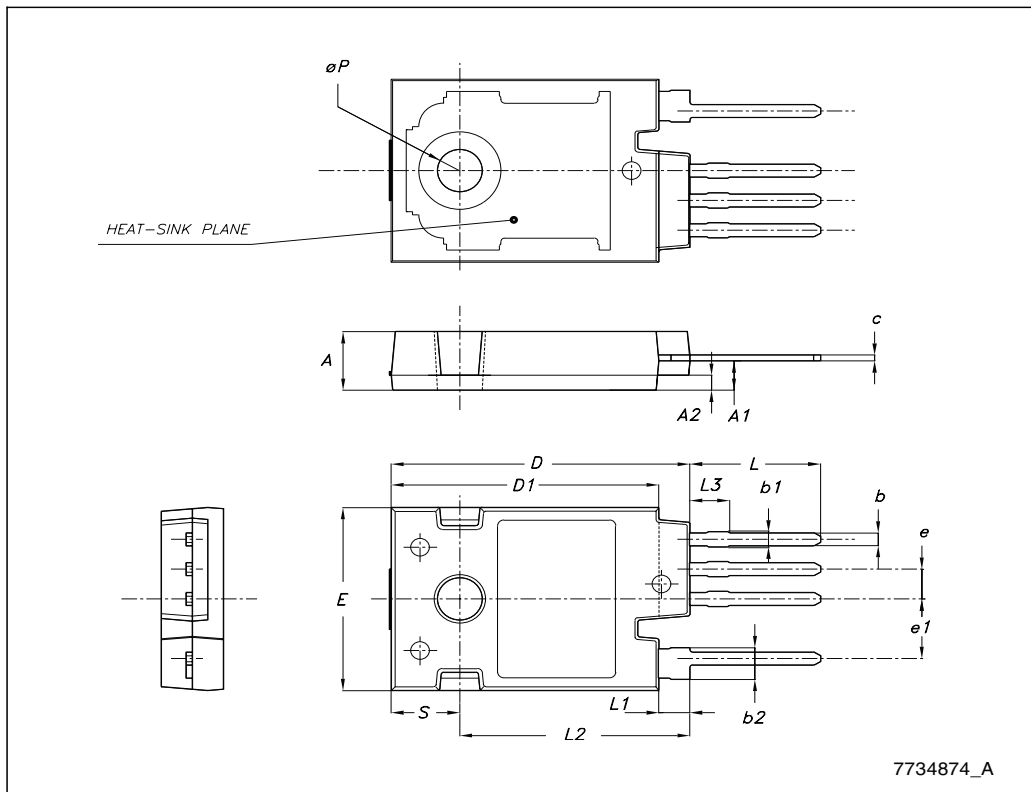


### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

|                                    |
|------------------------------------|
| <b>TO247-4L HV mechanical data</b> |
|------------------------------------|

| DIM. | mm.   |       |       |
|------|-------|-------|-------|
|      | MIN.  | TYP   | MAX.  |
| A    | 4.85  |       | 5.15  |
| A1   | 2.20  | 2.50  | 2.60  |
| A2   |       | 1.27  |       |
| b    | 0.95  | 1.10  | 1.30  |
| b1   | 1.10  |       | 1.50  |
| b2   | 2.50  |       | 2.90  |
| c    | 0.40  |       | 0.80  |
| D    | 23.85 | 24    | 24.15 |
| D1   |       | 21.50 |       |
| E    | 15.45 | 15.60 | 15.75 |
| e    |       | 2.54  |       |
| e1   |       | 5.08  |       |
| L    | 10.20 |       | 10.80 |
| L1   | 2.20  | 2.50  | 2.80  |
| L2   |       | 18.50 |       |
| L3   |       | 3     |       |
| øP   | 3.55  |       | 3.65  |
| S    |       | 5.50  |       |



## 4 Revision history

**Table 5. Document revision history**

| Date        | Revision | Changes   |
|-------------|----------|---|
| 27-Nov-2006 | 1        | First release.  |
| 19-May-2008 | 2        | Document status promoted from preliminary data to datasheet.                      |
| 10-Jun-2009 | 3        | Added <a href="#">Section 2.1: Electrical characteristics (curves) on page 4.</a> |



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